Unit: mm

#### TOSHIBA Photocoupler IRED & Photo-Triac

# TLP361J

Triac Drivers Programmable Controllers AC-Output Modules, Solid State Relays

TOSHIBA TLP361J consists of a zero-voltage-crossing turn-on phototriac optically coupled to an infrared emitting diode in a four-lead plastic DIP package.

- Peak off-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- On-state current: 100 mA (max)
- Isolation voltage: 5000 Vrms (min)
- Zero crossing Function
- •UL-recognized: UL 1577, File No.E67349

•cUL-recognized: CSA Component Acceptance Service No.5A

#### File No.E67349

•CQC-approved: GB4943.1,GB8898 Japan Factory

•VDE-approved: EN 60747-5-5 , EN 62368-1 (Note 1)

Note 1 : When a VDE approved type is needed, please designate the **Option(D4)**.

Maximum operating insulation voltage	: 890 Vpk
Maximum permissible overvoltage	: 8000 Vpk

#### ·Construction mechanical rating

	7.62 mm pitch TLPXXX type	10.16 mm pitch TLPXXXF type
Creepage distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation thickness	0.4 mm (min)	0.4 mm (min)

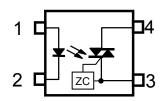
•Trigger LED current

	Trigger LED	current (mA)	
Classification* VT=3V, Ta=25°C		Ta=25°C	Marking of classification
	Min	Max	classification
(IFT7)		7	T7
Standard	_	10	T7、blank

\*Example: "(IFT7)"; "TLP361J(IFT7)"

(Note) When specifying the application type name for certification testing, be sure to use the standard product type name, e.g. TLP361J(IFT7): TLP361J

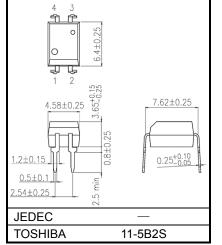




1: Anode

- 2: Cathode
- 3: Triac Terminal
- 4: Triac Terminal

Start of commercial production 2003-06



Weight: 0.26 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	lF	50	mA	
	Forward current derating (Ta ≥ 53°C)	∆I <sub>F</sub> /°C	-0.7	mA /°C	
	Peak forward current (100 µs pulse, 100 pps)	IFP	1	А	
ΓED	Reverse voltage		VR	5	V
	Diode power dissipation		PD	100	mW
	Diode power dissipation derating (Ta $\geq$ 53°C)		∆P <sub>D</sub> /°C	-1.4	mW/°C
	Junction temperature		Tj	125	°C
	Off-state output terminal voltage		VDRM	600	V
	On-state RMS current	Ta = 25°C	IT(RMS)	100	mA
		Ta = 70°C	П(RMS)	50	
or	On-state current derating (Ta ≥ 25°C)		∆I <sub>T</sub> /°C -1.1		mA /°C
Detector	Peak on-state current (100 µs pulse, 120 pps)		I <sub>TP</sub>	2	А
Ō	Peak non-repetitive surge current (Pw = 10 ms)		ITSM	1.2	А
	Output power dissipation		Po	300	mW
	Output power dissipation derating (Ta $\ge 25^{\circ}$ C)		ΔP <sub>0</sub> /°C -3.0		mW / °C
	Junction temperature		Tj	115	°C
Stor	age temperature range	T <sub>stg</sub>	-55~125	°C	
Оре	Operating temperature range			-40~100	°C
Lea	d soldering temperature (10 s)		T <sub>sol</sub>	260	°C
Isola	ation voltage (AC, 60 s, R.H. ≤ 60 %)	(Note 1)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pins 1 and 2 are shorted together and pins 3 and 4 are shorted together.

### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	VAC	_	_	240	Vac
Forward current	lF	15	20	25	mA
Peak on-state current	ITP	_	_	1	А
Operating temperature	T <sub>opr</sub>	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

# **Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_		10	μA
	Capacitance	CT	VF = 0 V, f = 1 MHz	_	30	_	pF
	Peak off-state current	IDRM	V <sub>DRM</sub> = 600 V	_	10	1000	nA
	Peak on-state voltage	VTM	I <sub>TM</sub> = 100 mA		1.7	3.0	V
Detector	Holding current	lΗ	—	_	0.6	_	mA
Dete	Critical rate of rise of off-state voltage	dv/dt	Vin = 240 Vrms, Ta = 85 °C (Note 2)	200	500		V/µs
	Critical rate of rise of commutating voltage	dv/dt(c)	Vin = 60 Vrms, I <sub>T</sub> = 15mA (Note 2)	_	0.2	_	V/µs

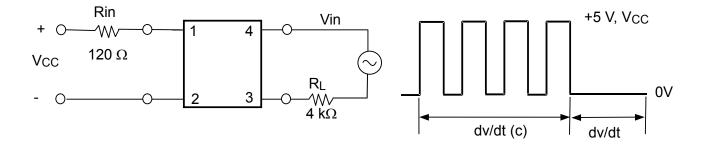
# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	IFT	V <sub>T</sub> = 3 V	_	_	10	mA
Inhibit voltage	VIH	IF = Rated IFT	_	—	20	V
Leakage in inhibited state	IIН	I <sub>F</sub> = Rated I <sub>FT</sub> V <sub>T</sub> = Rated V <sub>DRM</sub>	_	200	600	μA
Turn-on time	t <sub>ON</sub>	$V_D$ = 3 →1.5 V , R <sub>L</sub> = 20 Ω I <sub>F</sub> = Rated I <sub>FT</sub> X1.5	_	30	100	μs

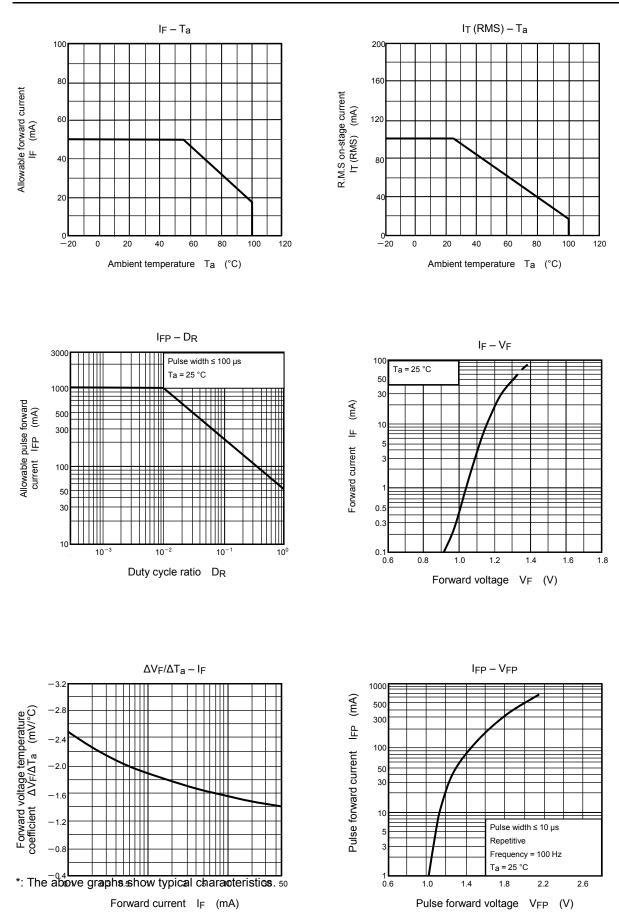
# Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	Vs = 0 V , f = 1 MHz	_	0.8	—	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H. ≤ 60 %	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage	BVS	AC, 60 s	5000	_	_	Vrms

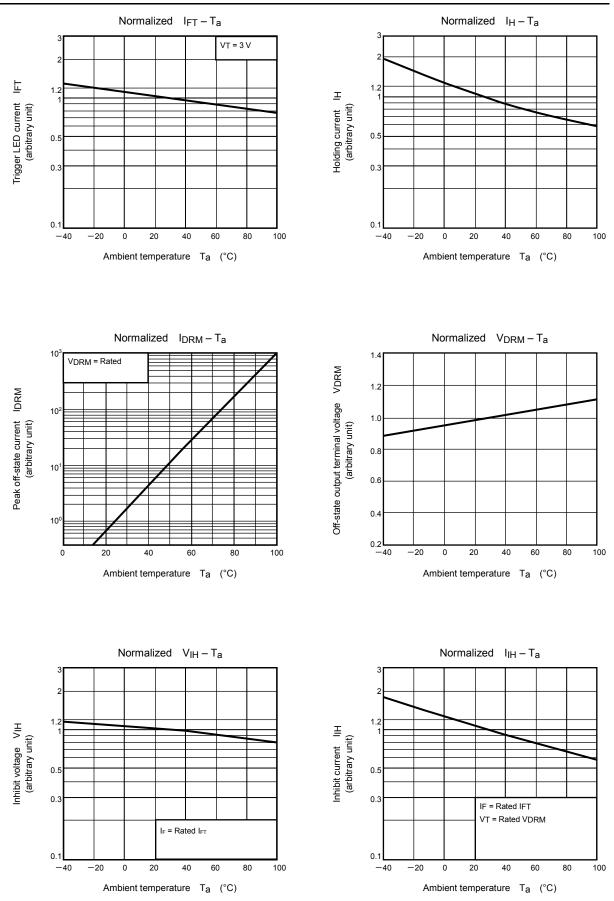
(Note 2): dv/dt test circuit



TLP361J



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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